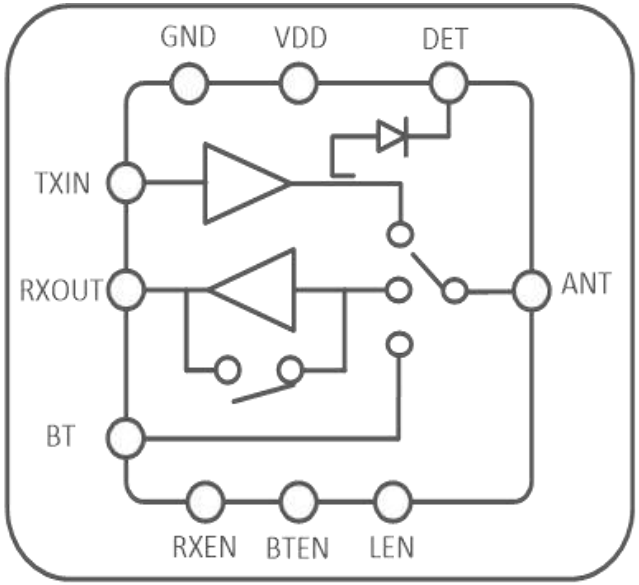
RFX8422S CMOS Single-Chip/Single-Die 2.4GHz RFeIC with PA, LNA & SP3T for Dual-Mode WiFi/Bluetooth Operation in Mobile Devices

Evaluation Board Test Results Summary & Technical Notes

RFX8422S 2.4GHz WLAN/BT RFeIC with PA, LNA, SP3T

Functional Block Diagram



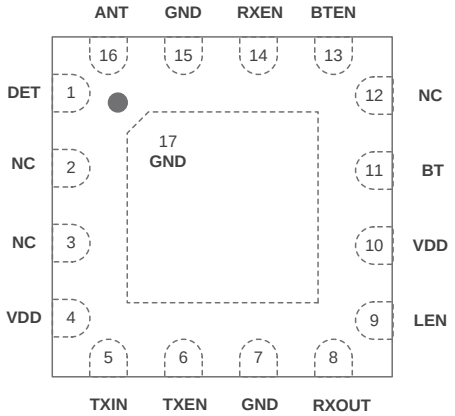
Product Overview

- Pure CMOS Single-Chip, Single-Die RF Front-End IC
- PA + LNA + SP3T Switch + Harmonic Filters
- High Linearity PA 802.11n/ac WLAN & BT
- Low Noise Figure WLAN Receive LNA with Bypass for Near Range Operation
- 2.4 – 2.5 GHz Frequency Band
- Direct Battery Operation
- Complete On-Chip RF Decoupling and DC Block Capacitors – No External Inductors
- 2.5mm x 2.5mm x 0.45 mm, 16L QFN Package

RFX8422S Applications

- Smartphones, Feature Phones and MIDs with WLAN/Bluetooth
- WLAN/Bluetooth Platforms Requiring Shared Antenna
- Laptop / Netbook / Smartbook with Embedded WiFi & Bluetooth
- Portable Platforms with Integrated 802.11n/ac and Bluetooth

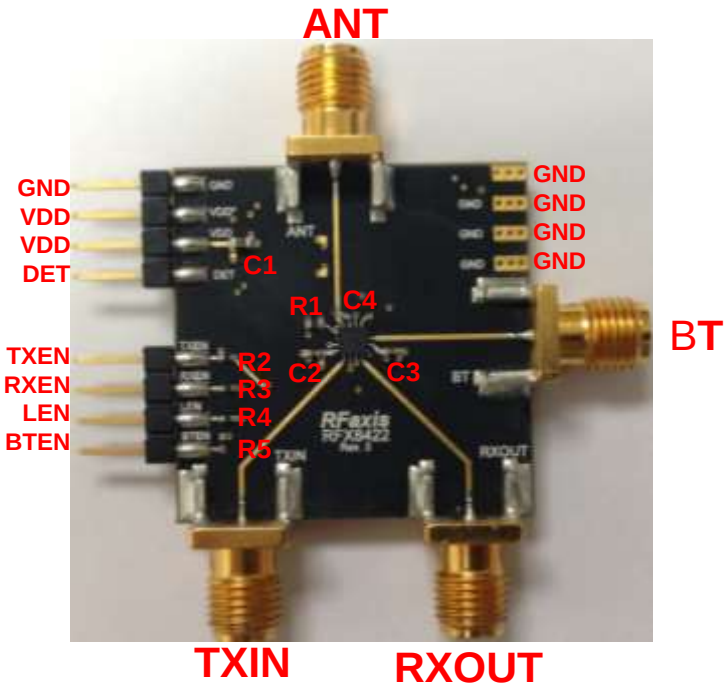
RFX8422S Pin-out and Pin Description



(Top "See-Through" View)

Pin Number	Pin Name	Description
1	DET	PA Power Detector Output
2, 3, 12	NC	Not Connected Internally. Can be Grounded or Left Open
4, 10	VDD	DC Voltage Supply
5	TXIN	WLAN TX Signal Port from the Transceiver: DC Shorted to GND
6	TXEN	CMOS Logic Control to Enable WLAN Transmit
7, 15, Paddle	GND	Ground – Must be Connected to Ground
8	RXOUT	WLAN RX Signal Port to the Transceiver: DC Shorted to GND
9	LEN	CMOS Logic Control to Enable LNA. Use to switch between the LNA and Bypass modes
11	BT	RF signal Port from/to the Bluetooth Transceiver: DC Shorted to GND
13	BTEN	CMOS Logic Control to Enable Bluetooth
14	RXEN	CMOS Logic Control to Enable WLAN Receive
16	ANT	RF Signal Port to/from the Antenna: DC Shorted to GND

RFX8422S Eval Board, DC Bias and Control Logic



Recommended BOM

Designator	Value	Footprint	Notes
C1	2.2uF	0402	X5R/X7R
C2	220pF	0402	X5R/X7R
C3	1uF	0402	X5R/X7R
C4	0.3pF	0402	COG
R1	10KΩ	0402	Det. Load
R2, R3, R4, R5	1KΩ	0402	*

* Only need if the control pin is directly connected to VDD.

Control Logic Truth Table

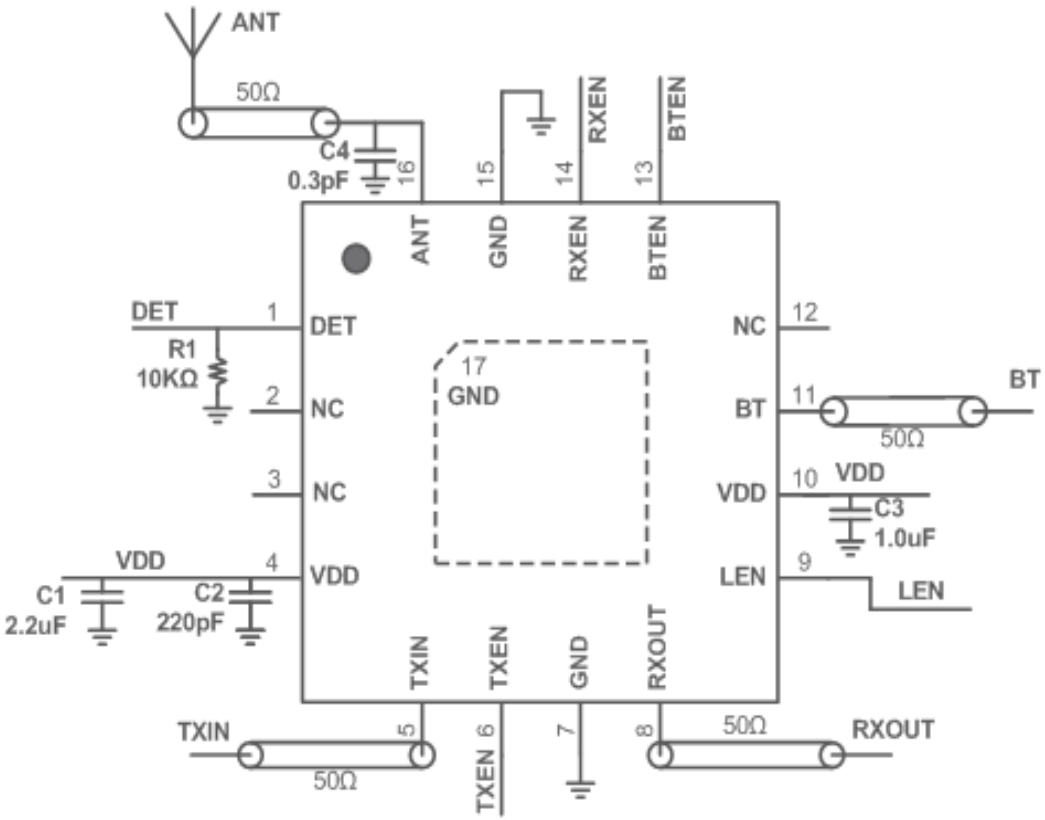
TXEN	BTEN	RXEN	LEN	Mode of Operating
0	0	0	0	Shutdown Mode
1	0	0	0	WLAN Transmit Mode
0	0	1	1	WLAN Receive. High Gain Mode
0	0	1	0	WLAN Receive. Bypass Mode
0	1	0	0	Bluetooth Transmit/Receive Mode

Note: "1" denotes high voltage state (> 1.2V) at Control Pins
"0" denotes low voltage state (< 0.3V) at Control Pins

Evaluation Board Information:

- 4-Layer Stack, 10mil/40mil/10mil
- FR4 with εr=4.5, tan δ = 0.02 (Typ)
- RFIN, RFOUT trace losses are ~0.25dB @ 2.4GHz – 2.5GHz
- Results in following slides are referenced to device pins with the trace loss de-embedded
- VDD should be on before applying ctrl signals
-VDD Nominal 3.6 Vdc. Operational from 2.9 to 4.5 Vdc with limitations.

Recommended Application Schematic and BOM



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C3	1uF	0402	X5R/X7R
C4	0.3pF	0402	COG
R1	10KΩ	0402	*

* Detector Voltage will vary with different resistor loads.

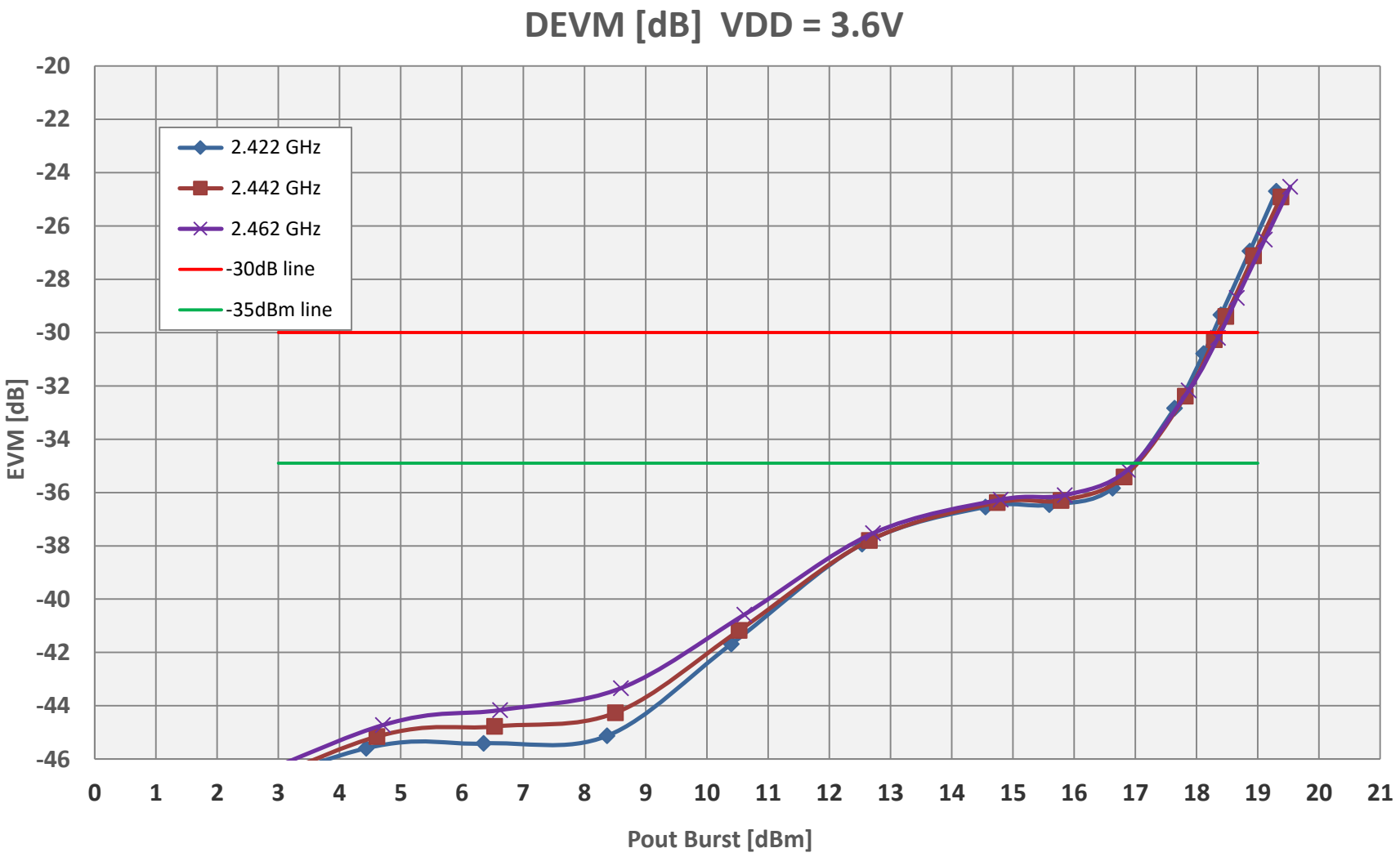
Nominal VDD = 3.6 Vdc
Operation from 2.9 to 4.5 Vdc with limitations

EVB Signal Loss De-Embedding

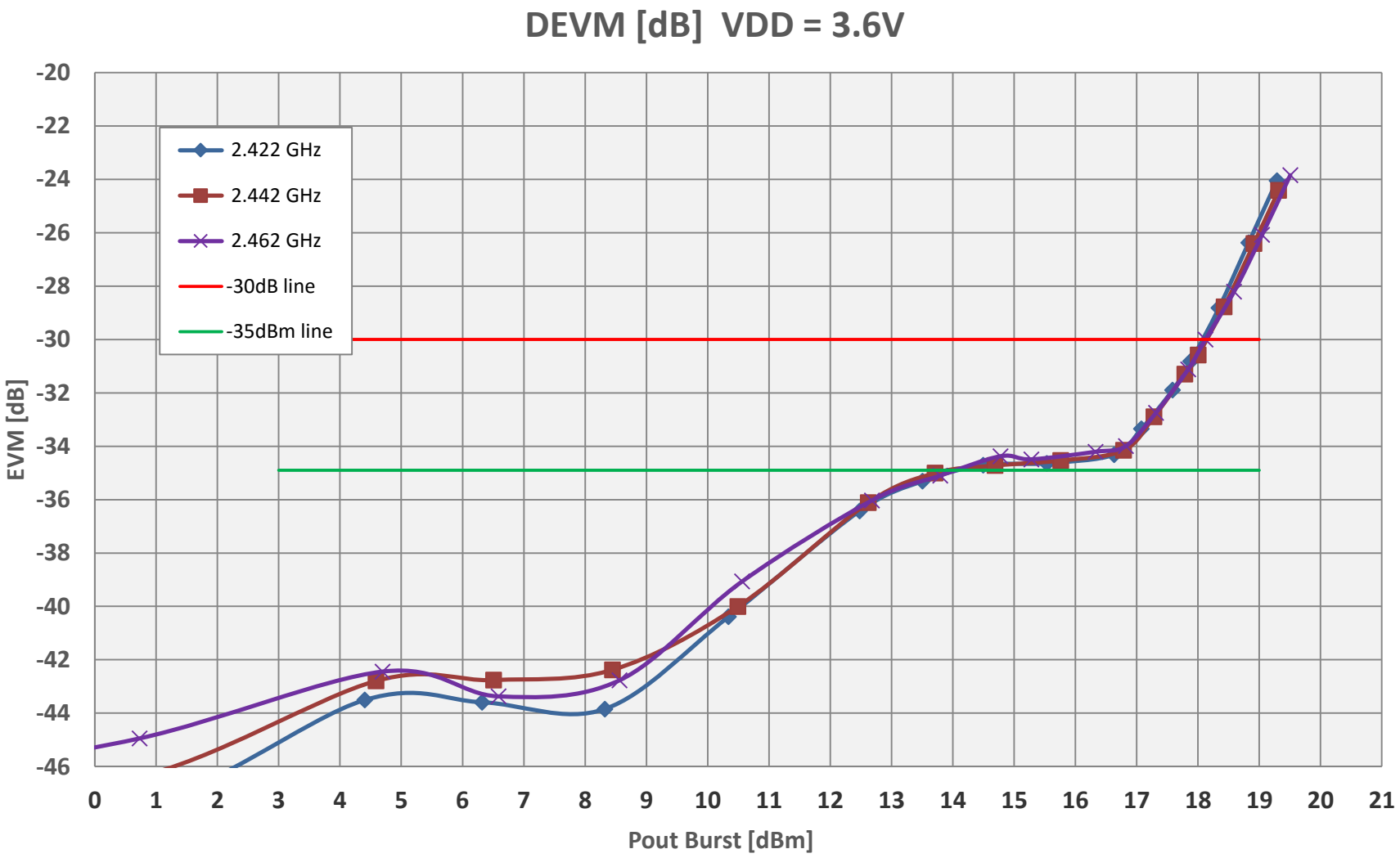
RF Signal	Loss
ANT	.20 dB
TX	.20 dB
RX	.25 dB
BT	.25 dB

Total EVB Loss Includes the Trace and Connector

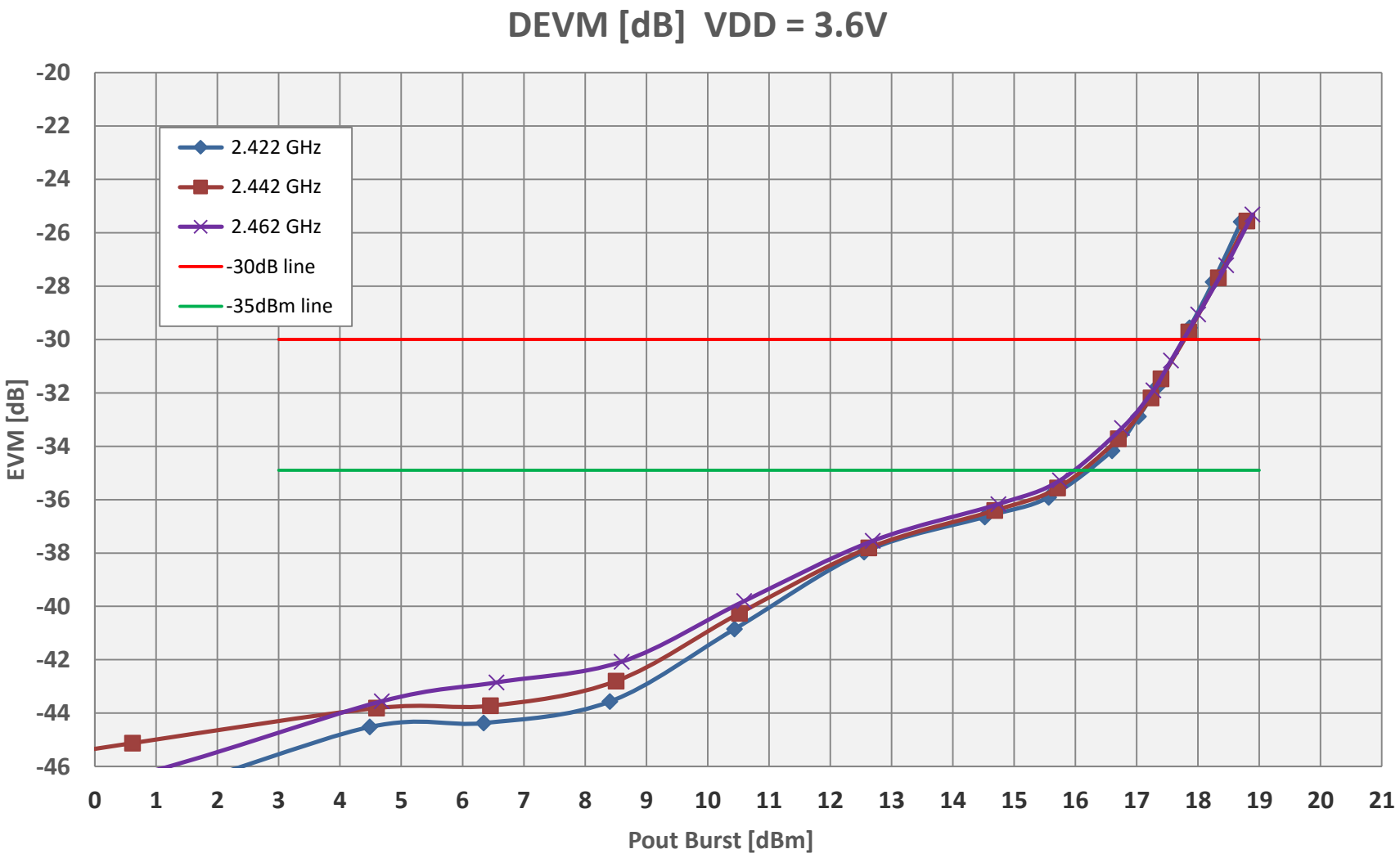
RFX8422S DEVM vs. Output Power over Frequency
802.11g 64 QAM



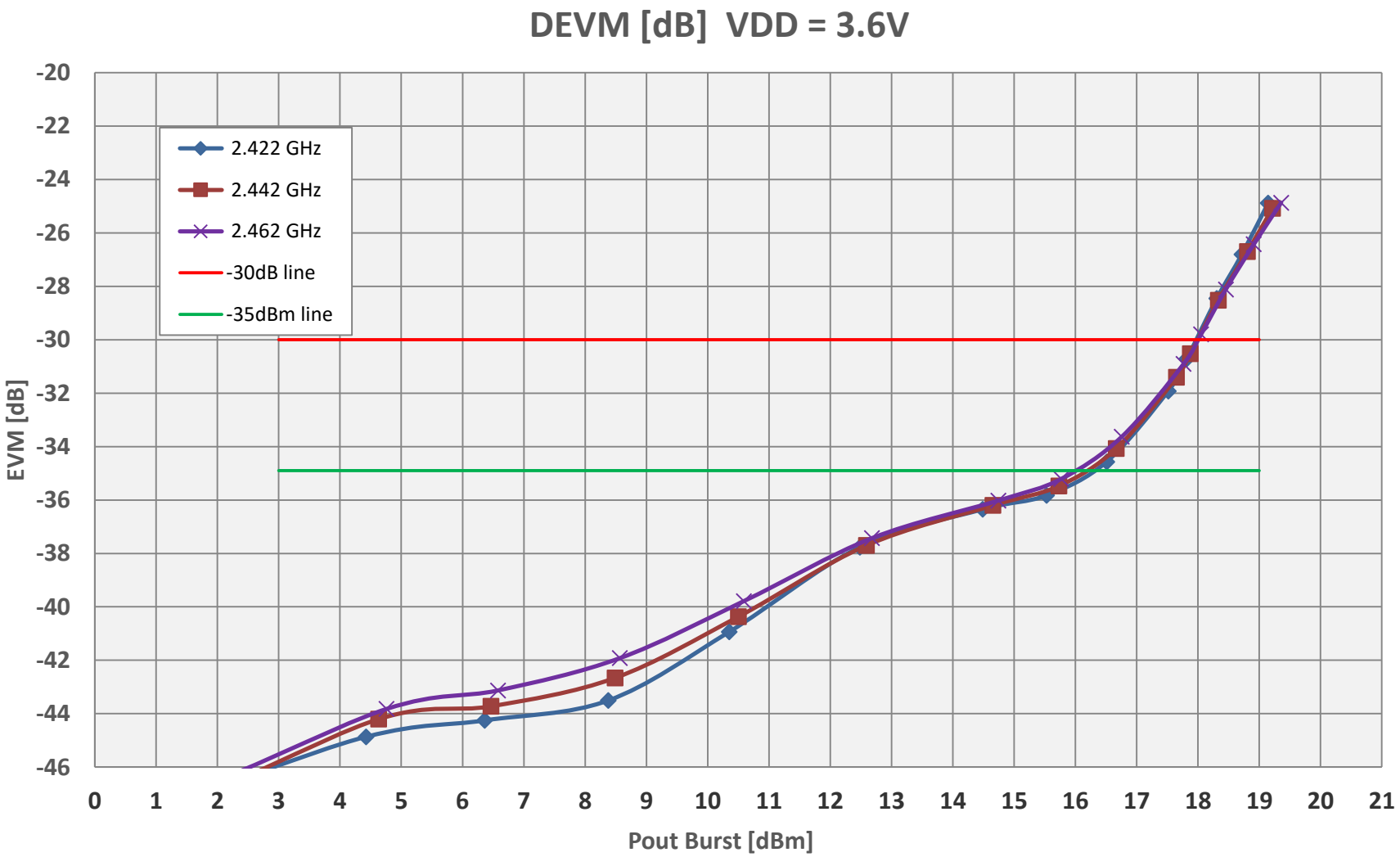
RFX8422S DEVM vs. Output Power over Frequency
802.11n HT20 MCS7



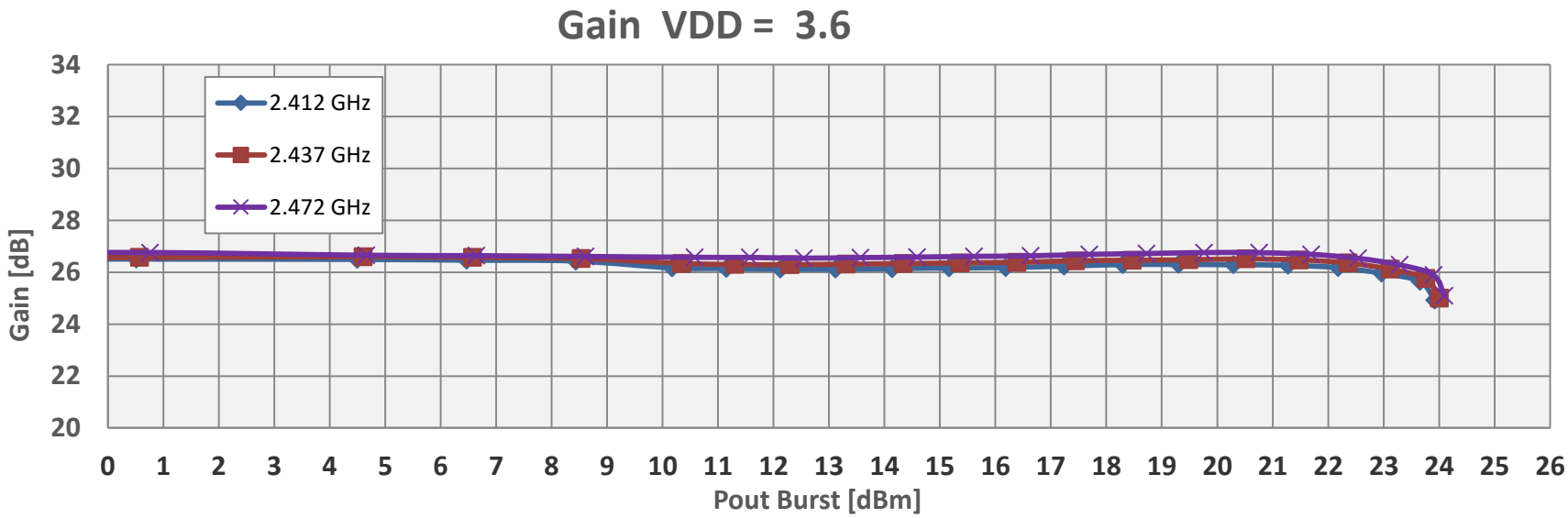
RFX8422S DEVM vs. Output Power over Frequency
802.11n HT40 MCS7

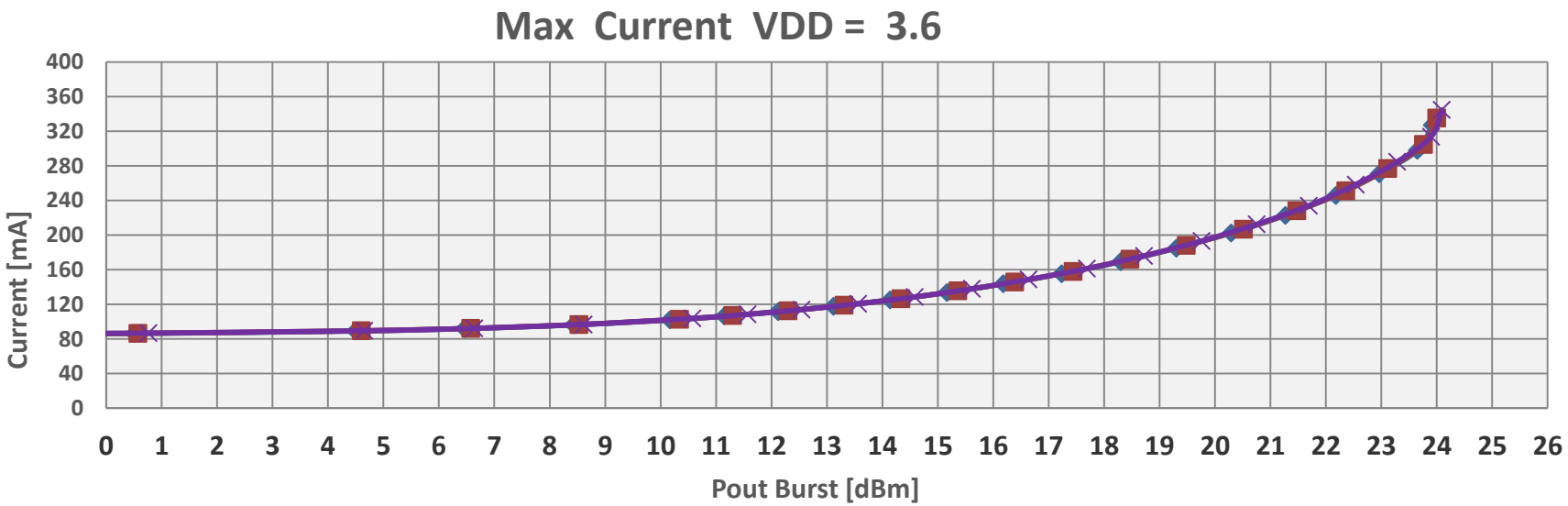


RFX8422S DEVM vs. Output Power over Frequency
802.11ac VHT40 MCS9

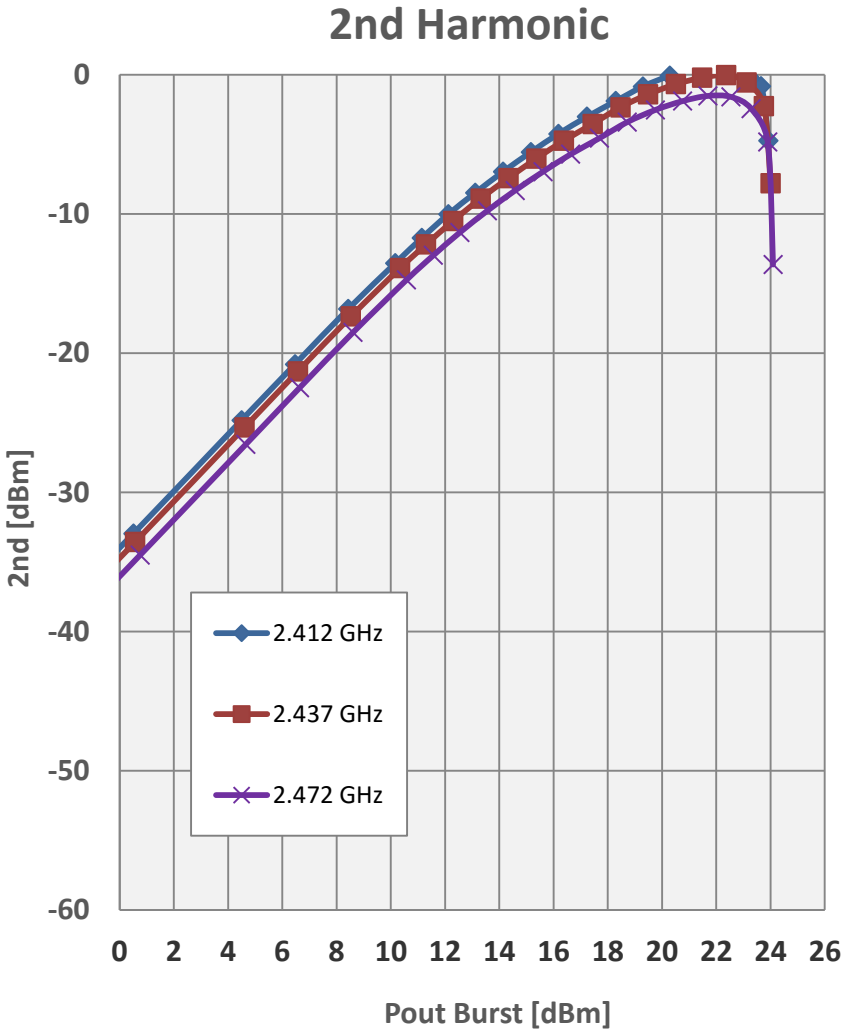


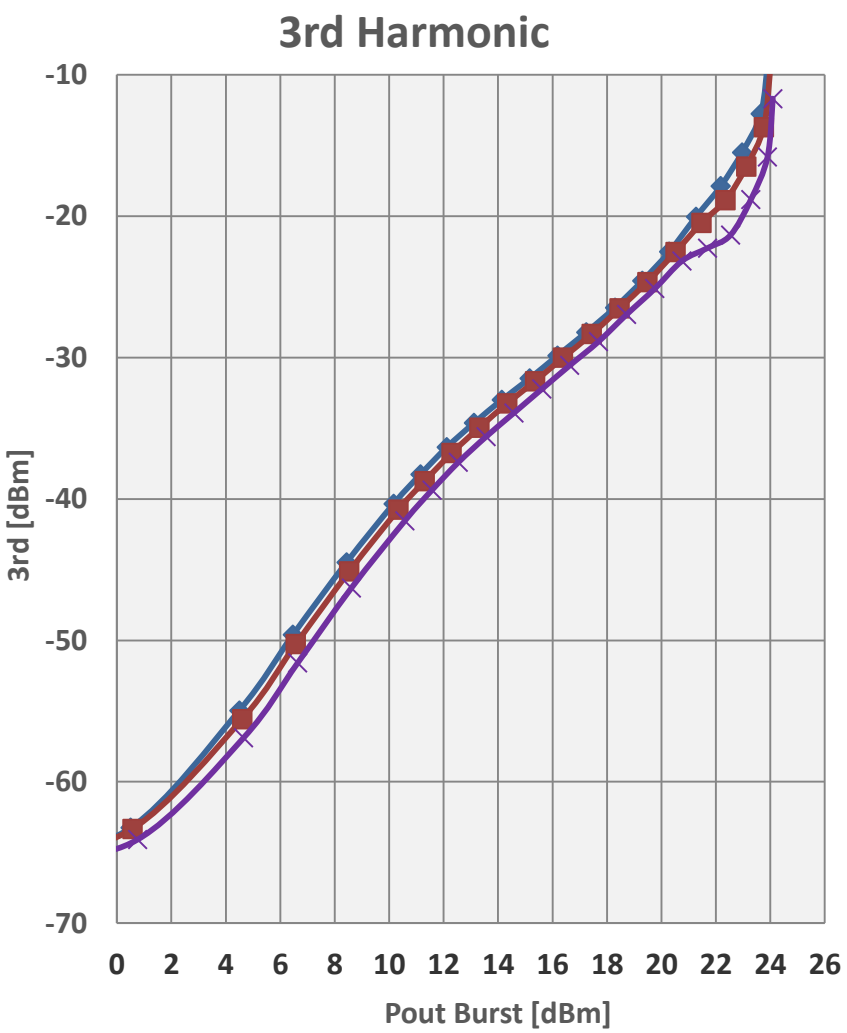
RFX8422S Gain and Current over Frequency
VDD = 3.6V



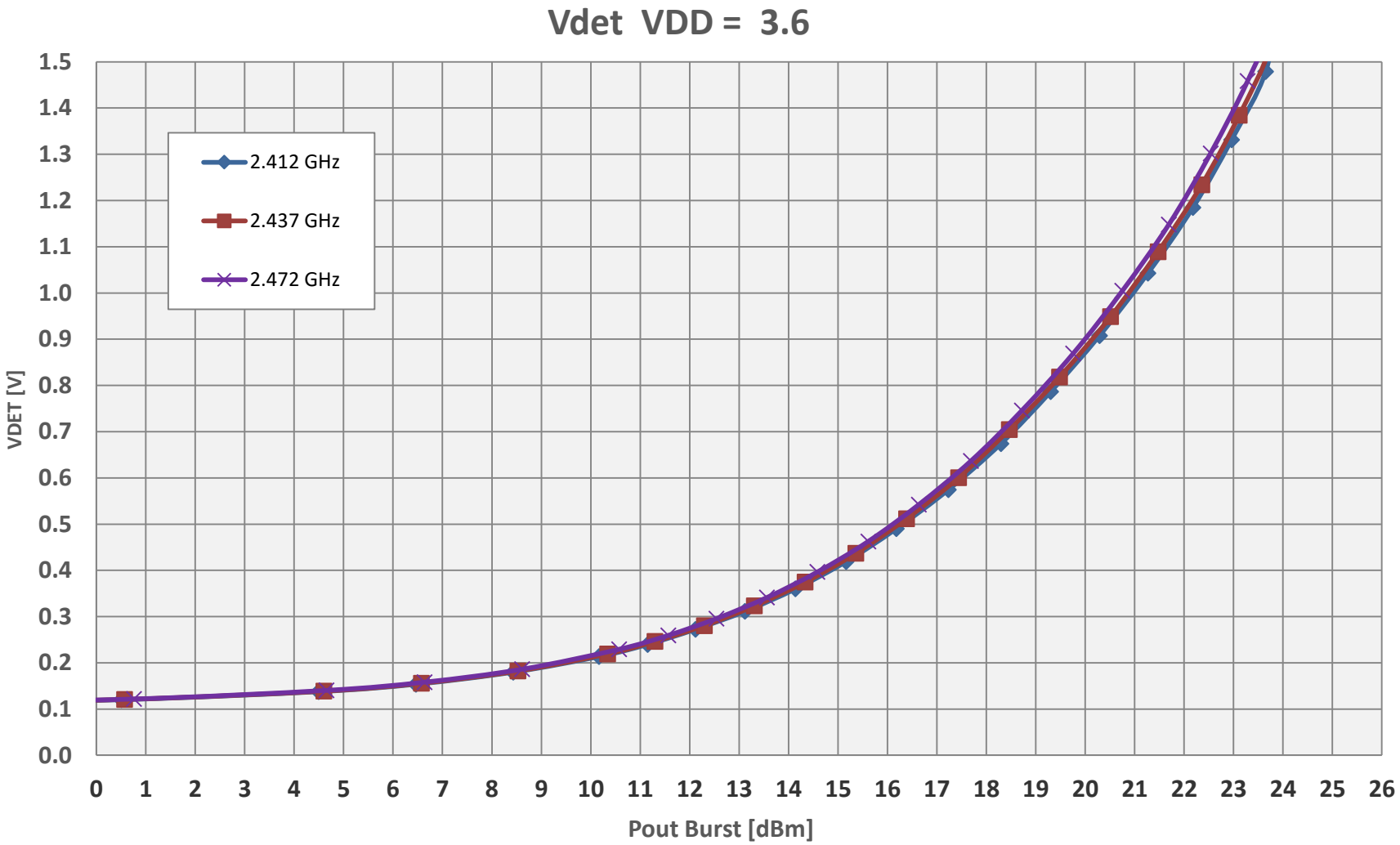


RFX8422S CW Harmonics vs. Output Power over Frequency
VDD = 3.6V



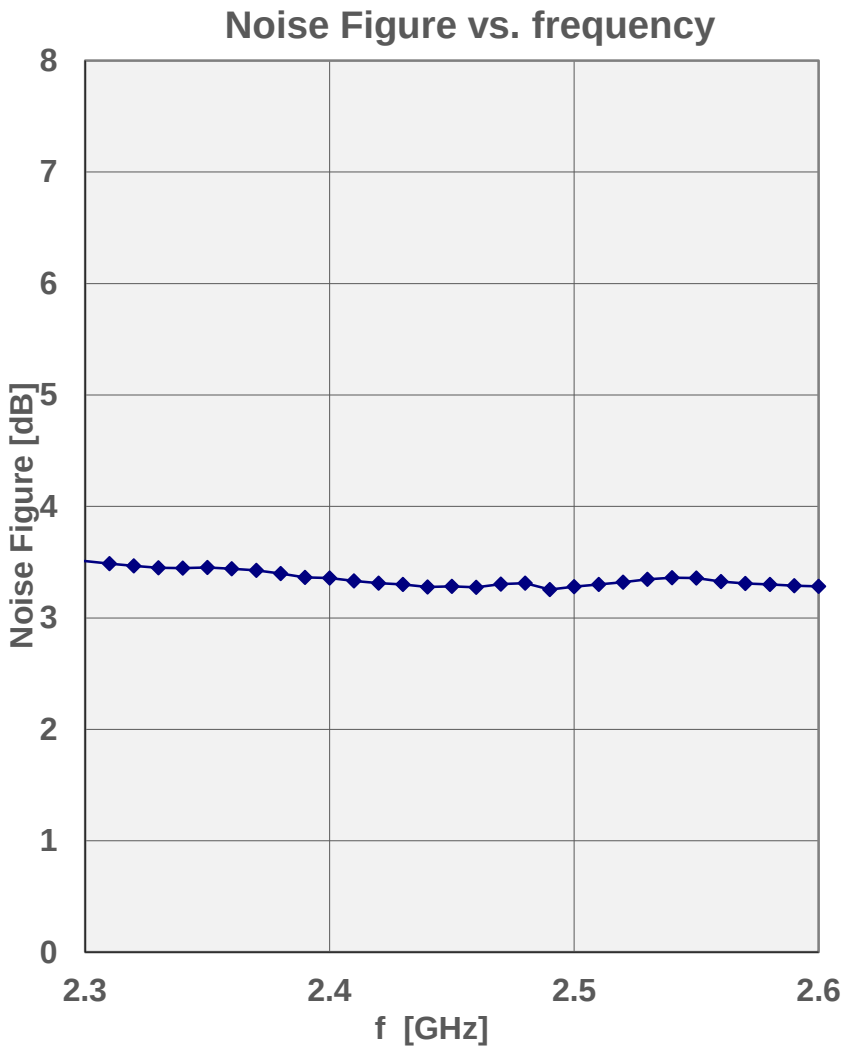


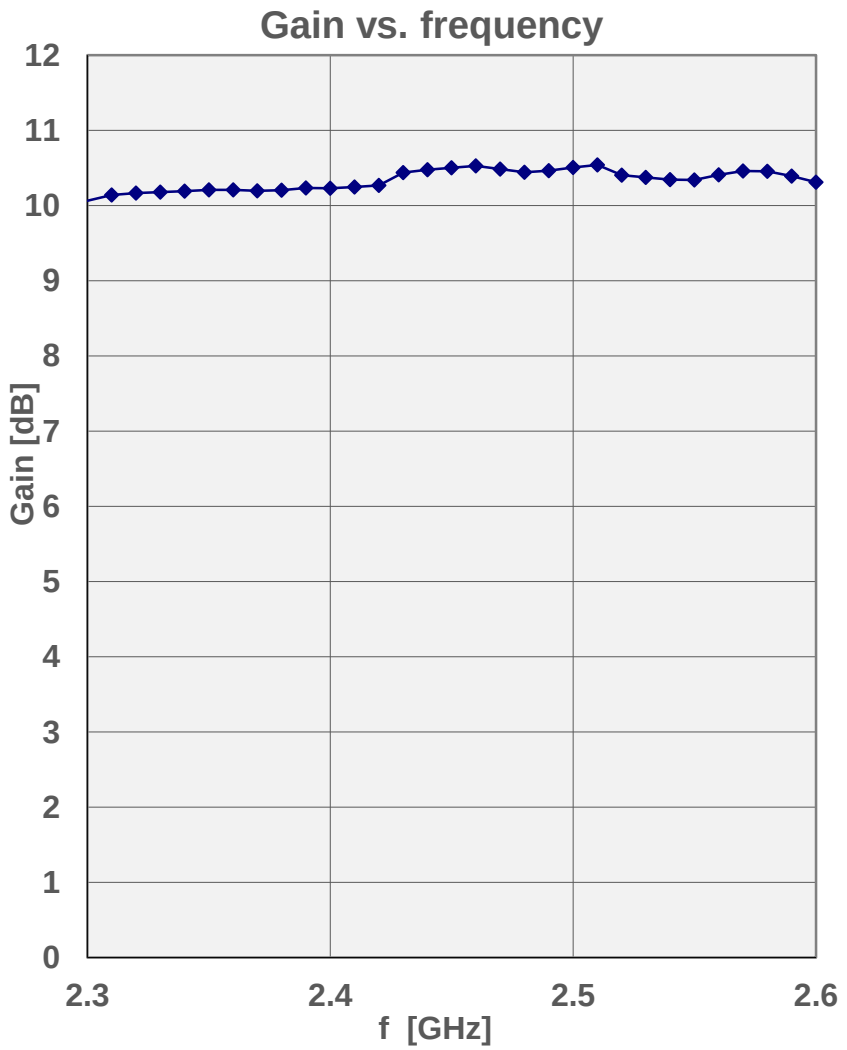
RFX8422S Detector Output Voltage vs. Pout, over Frequency CW Signal



Detector voltage measured with 10kΩ load. Detector voltage will be vary with different resistor load values.

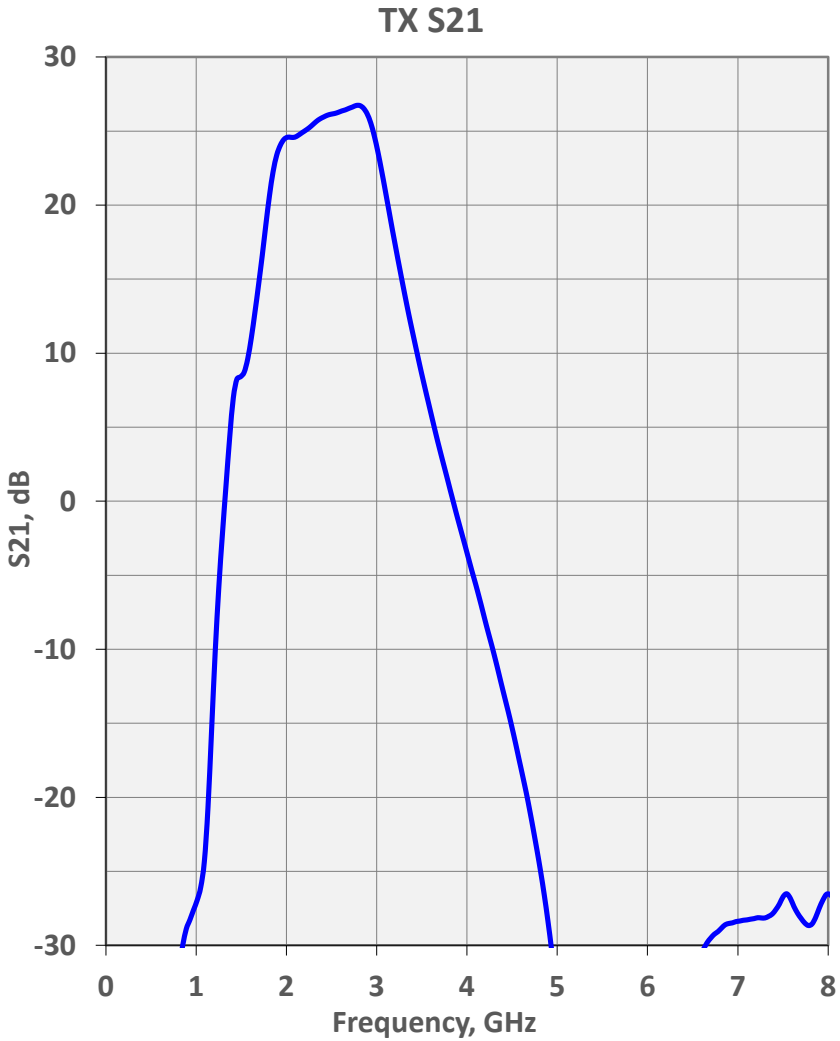
RFX8422S LNA Gain and Noise Figure vs. Frequency
VDD = 3.6V

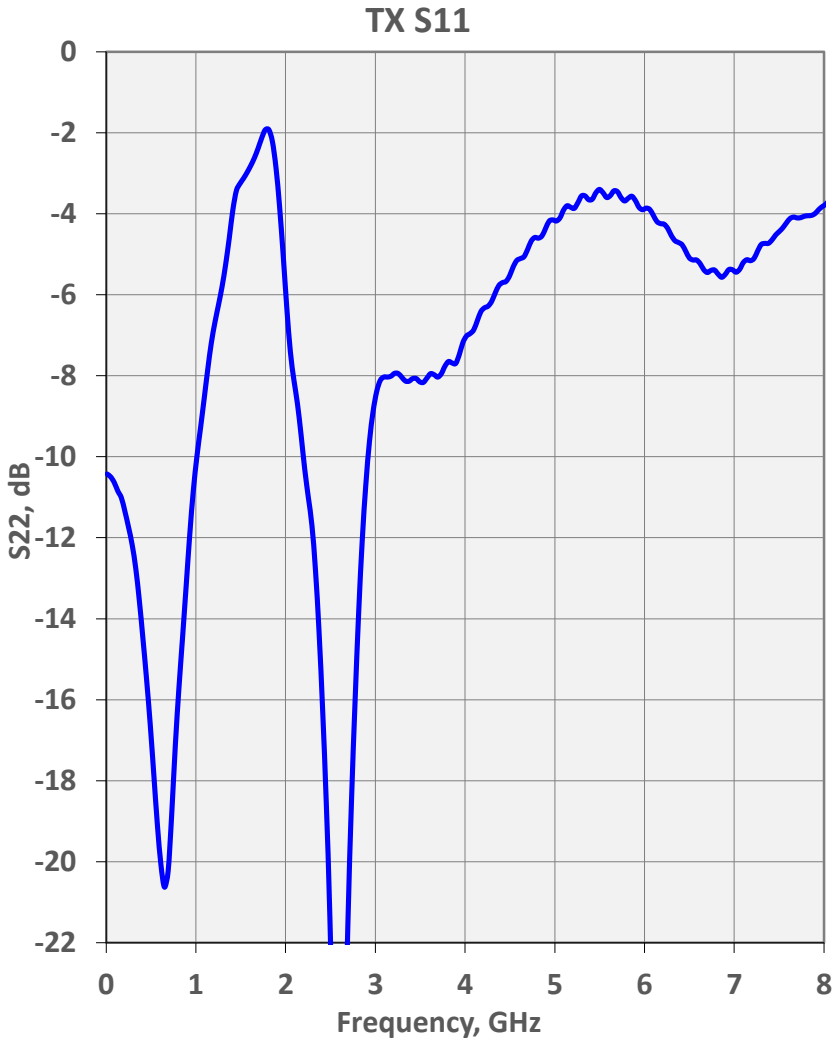




RXEN=High, LEN=High, TXEN=BTEN=Low, Iq= 12 mA

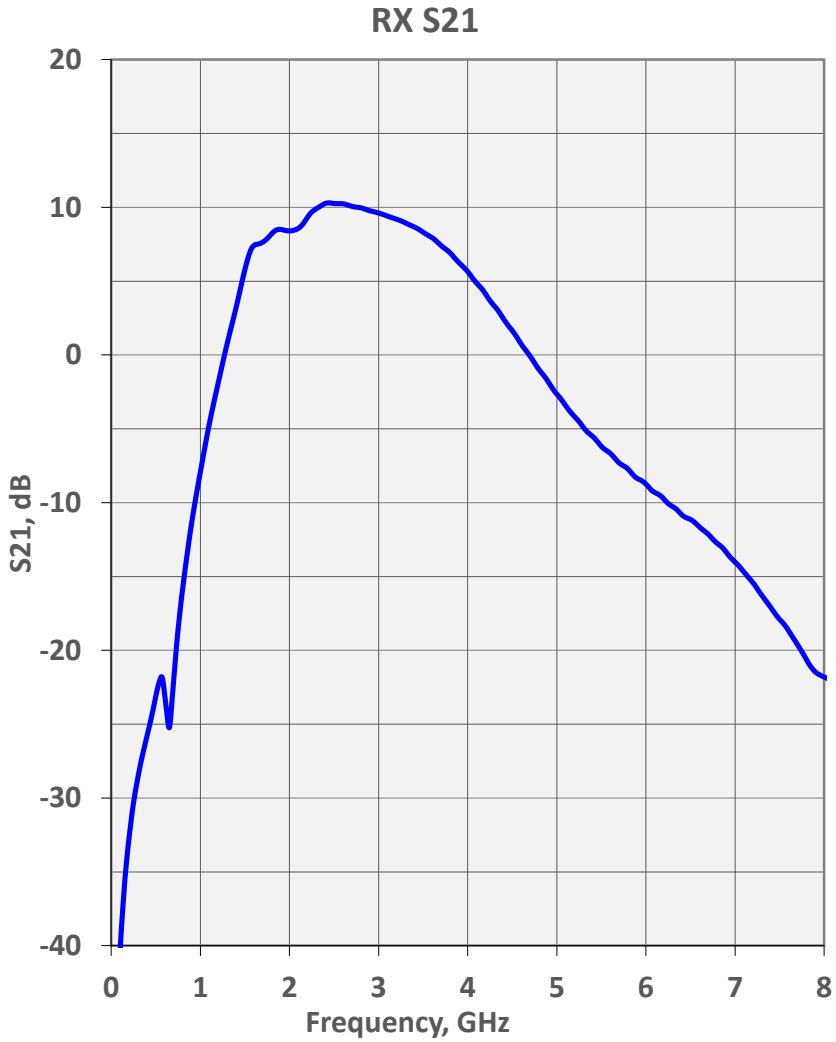
RFX8422S TX Small-Signal S21, S11

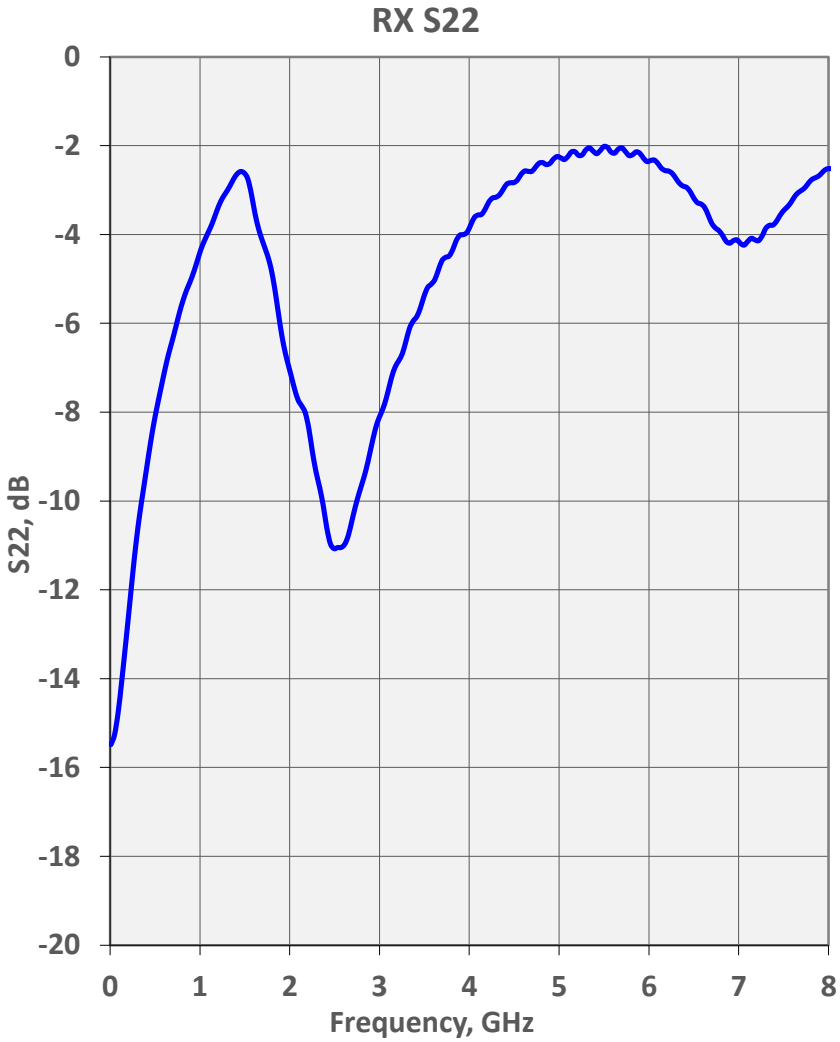




TXEN=High, RXEN=BTEN=Low, Icq~90mA @ VDD=3.6V

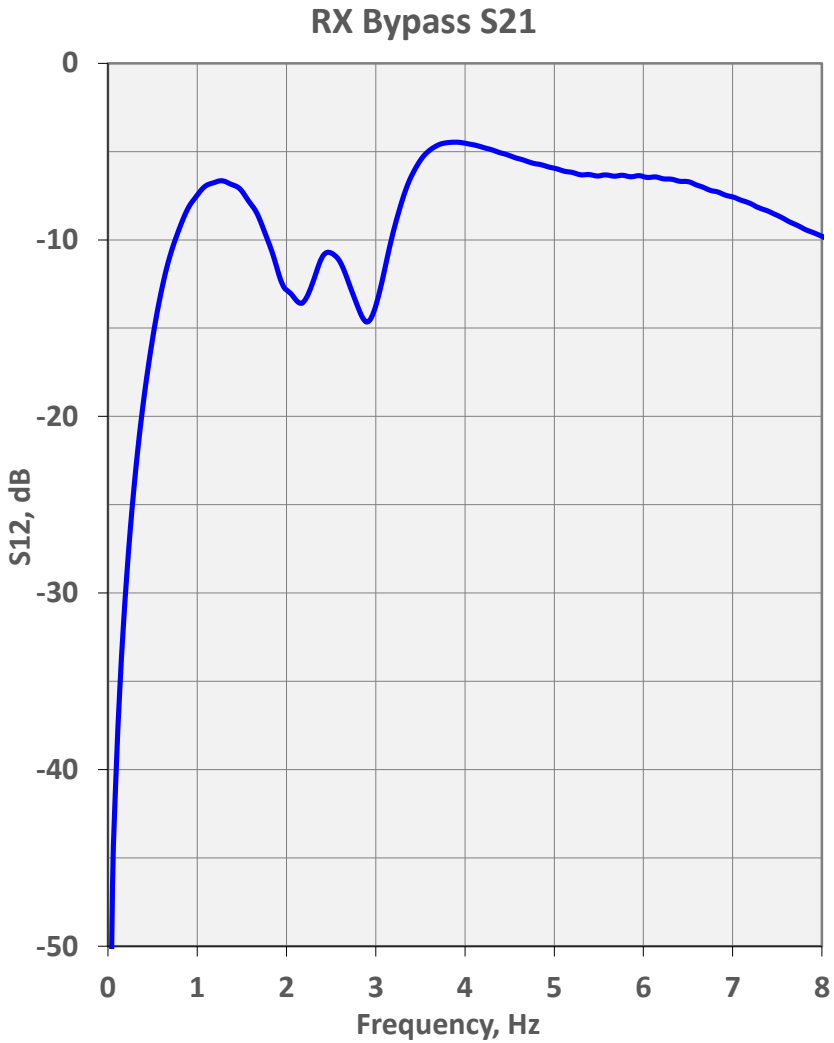
RFX8422S RX Small-Signal S21, S22



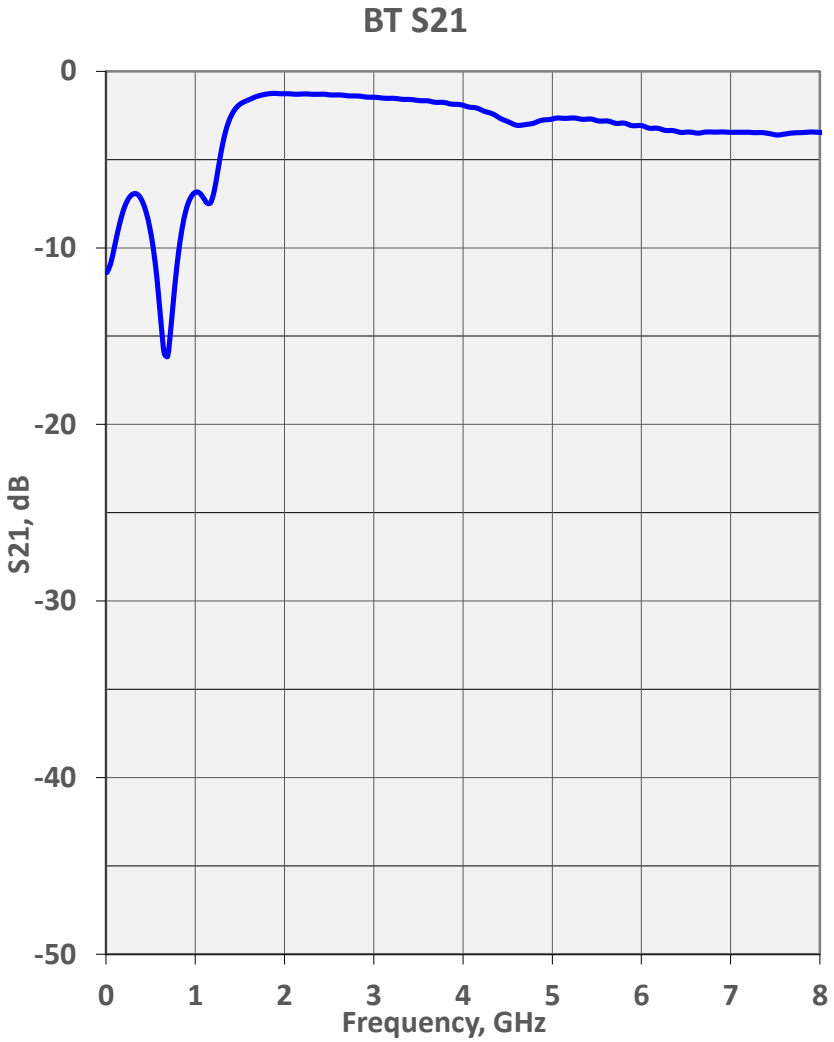


RXEN LEN=High, TXEN=BTEN=Low, LNA Iq= 12 mA

RFX8422S RX Bypass and BT Small-Signal S21



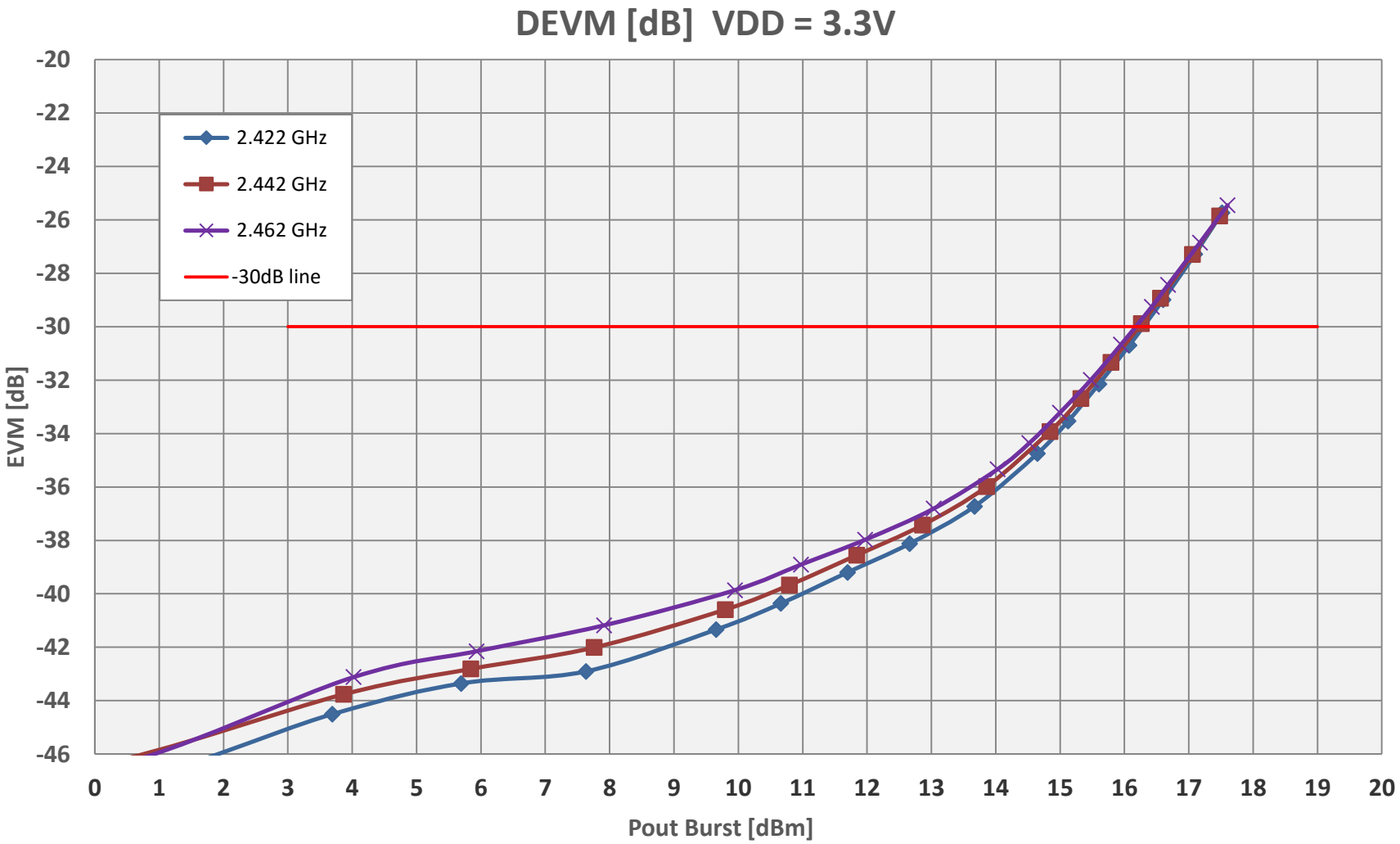
TXEN LEN BTEN=Low, RXEN=High, Iq= 1 mA



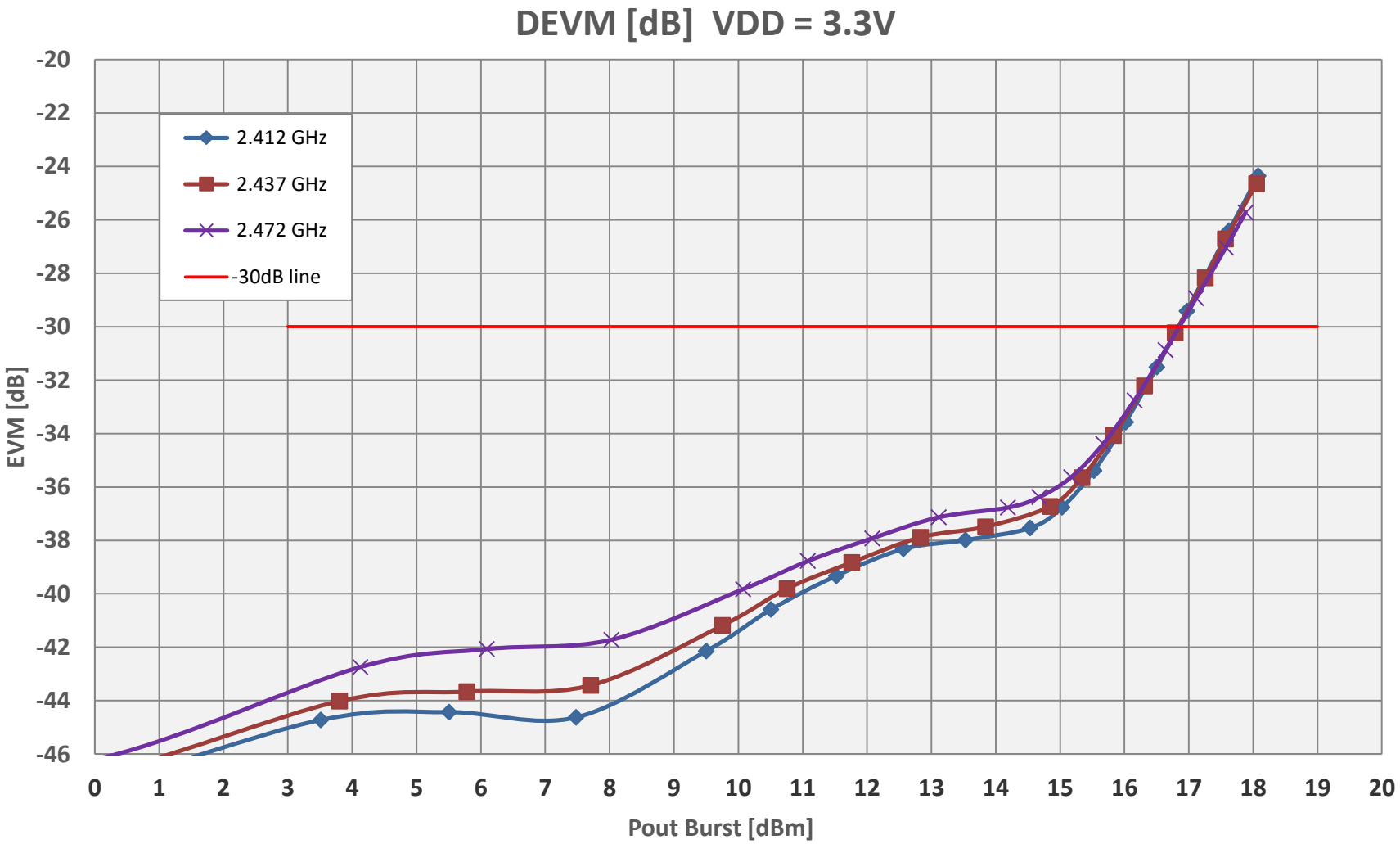
TXEN RXEN LEN=Low, BTEN=High, Iq= 1 mA

RFX8422S
VDD = 3.3V
Supplemental Data

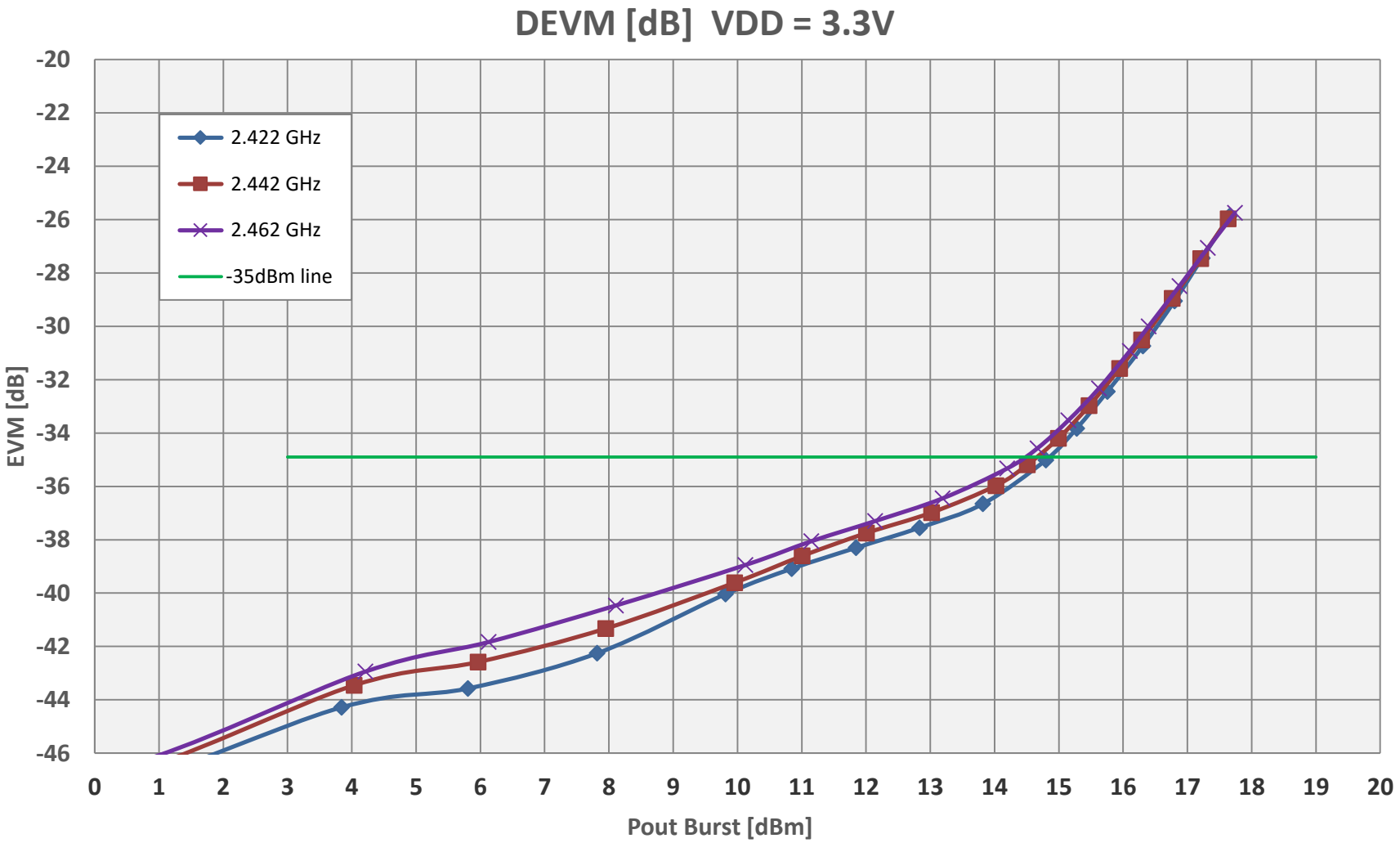
RFX8422S DEVM vs. Output Power over Frequency
802.11n HT40 MCS7



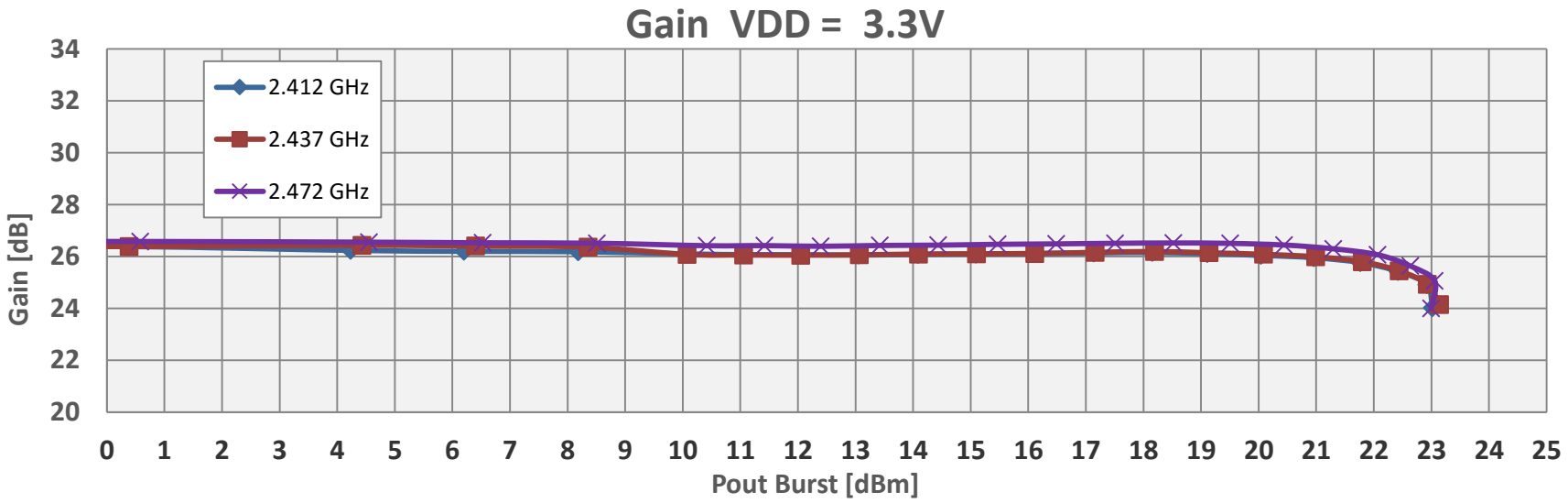
RFX8422S DEVM vs. Output Power over Frequency
802.11n HT20 MCS7

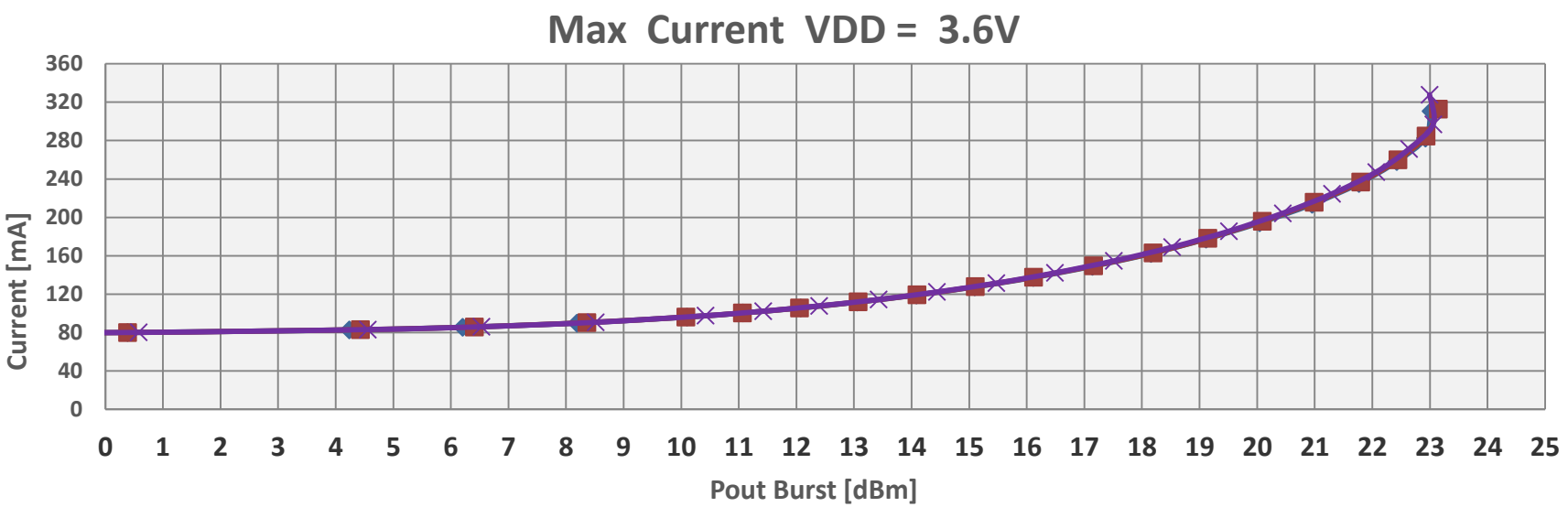


RFX8422S DEVM vs. Output Power over Frequency
802.11ac HT40 MCS9

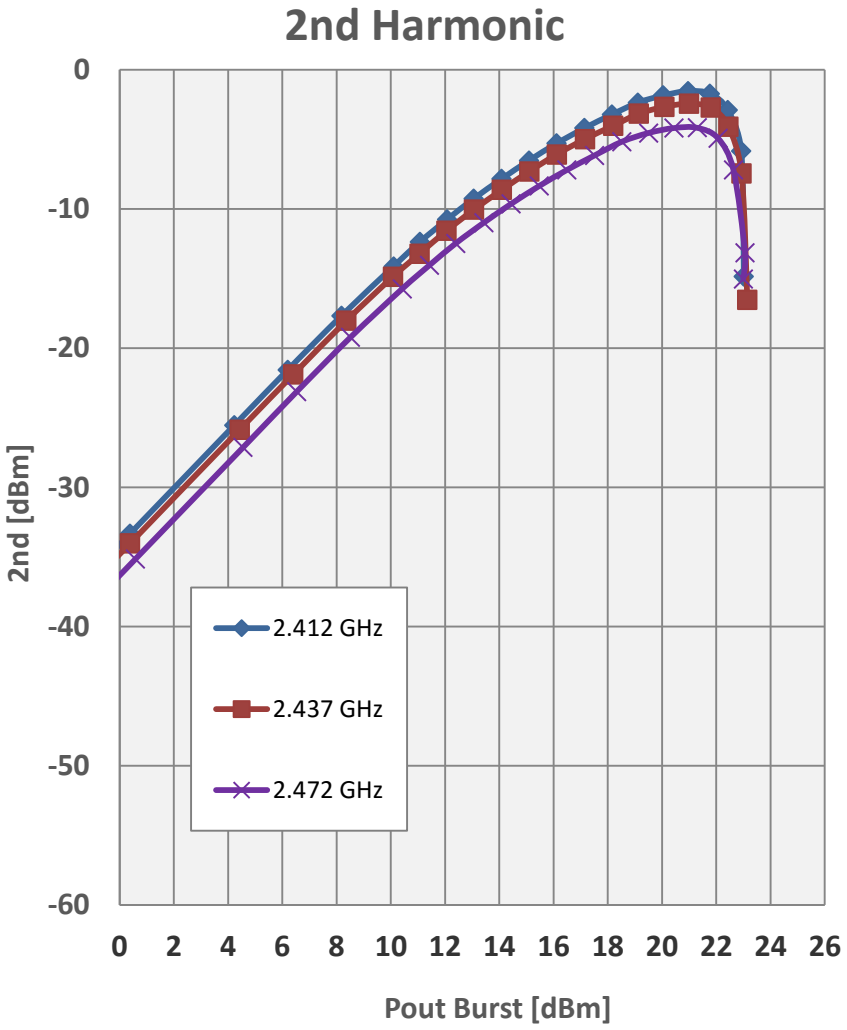


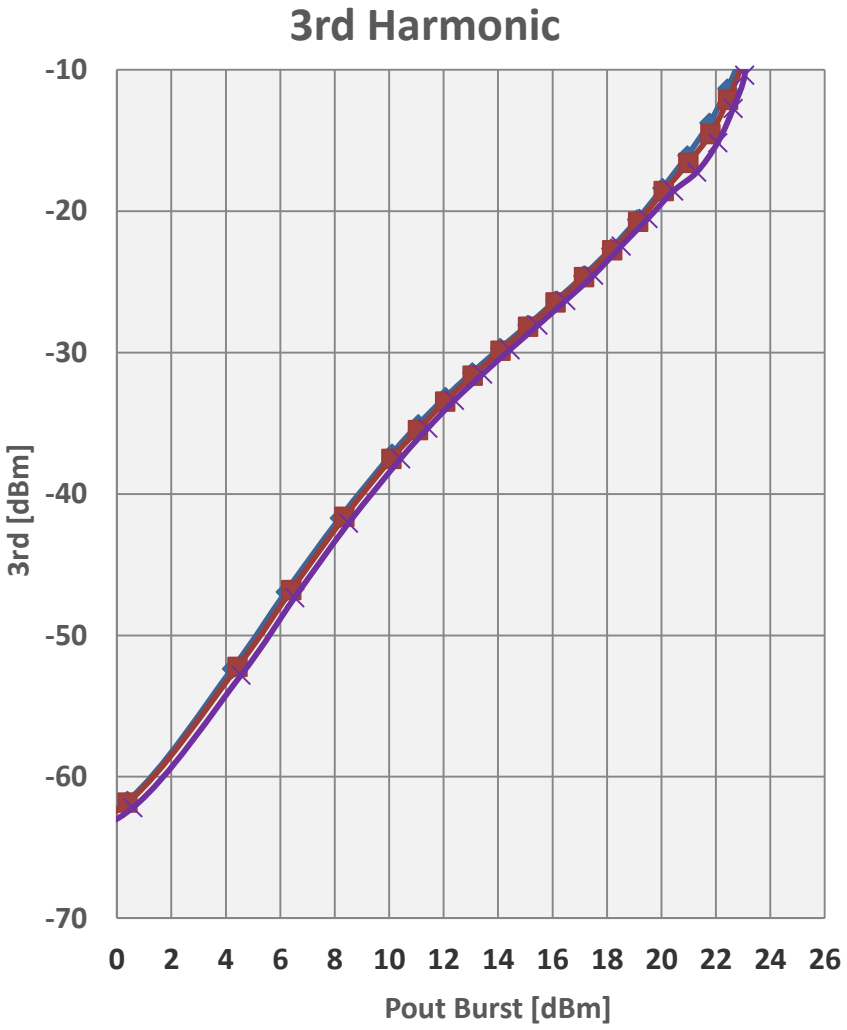
RFX8422S CW Gain and Current over Frequency
VDD = 3.3V



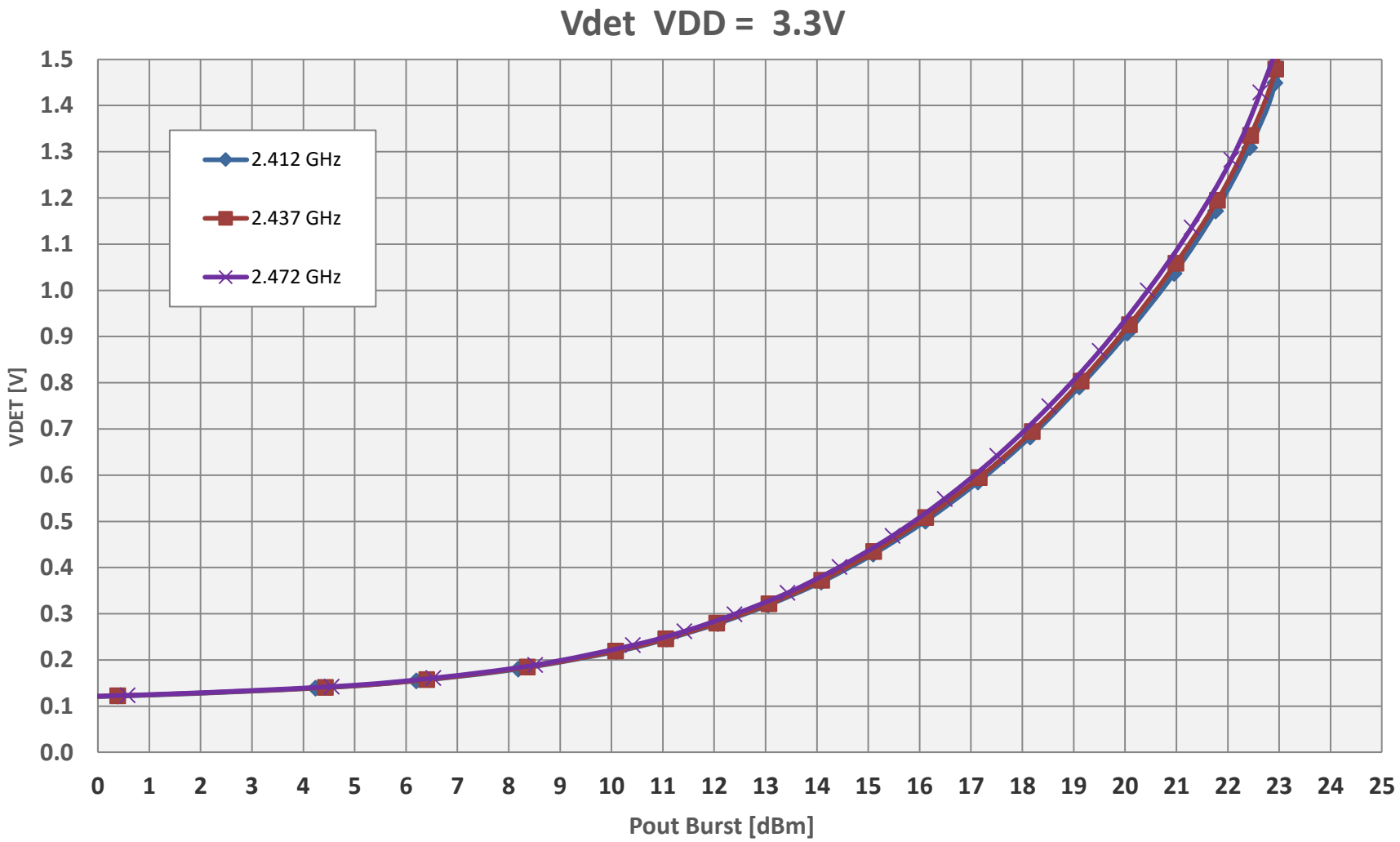


RFX8422S CW Harmonics over Frequency
VDD = 3.3V



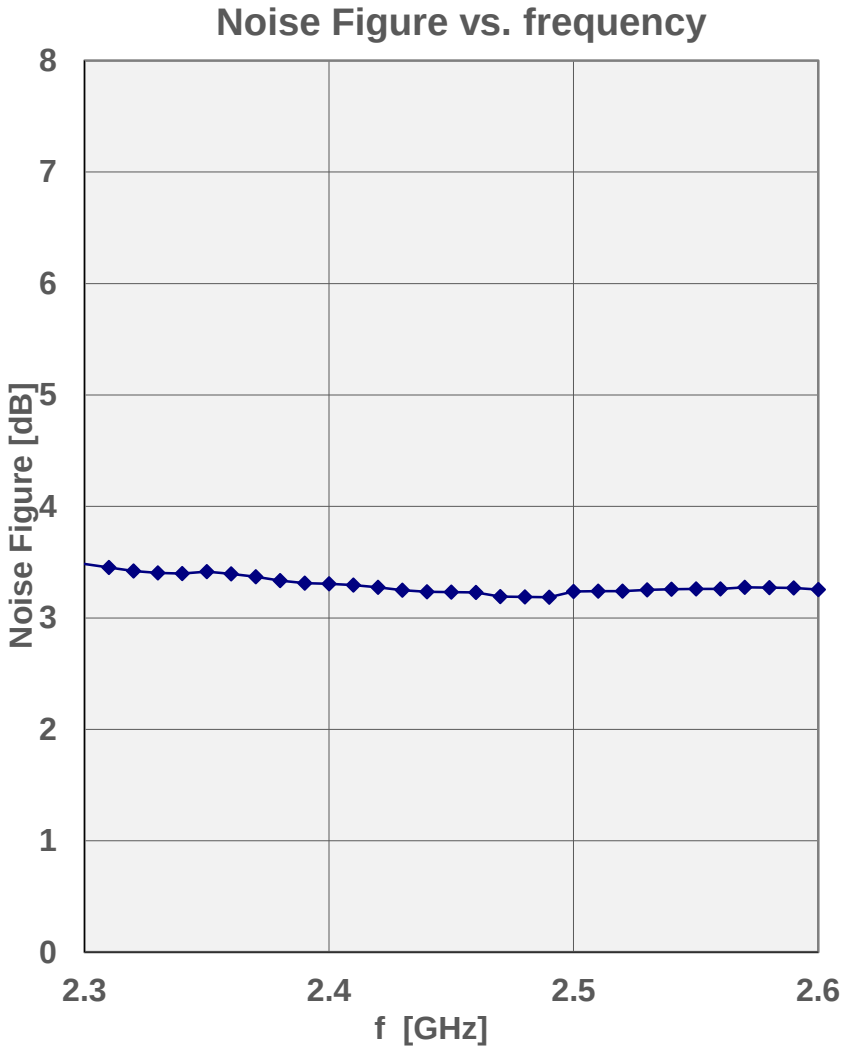


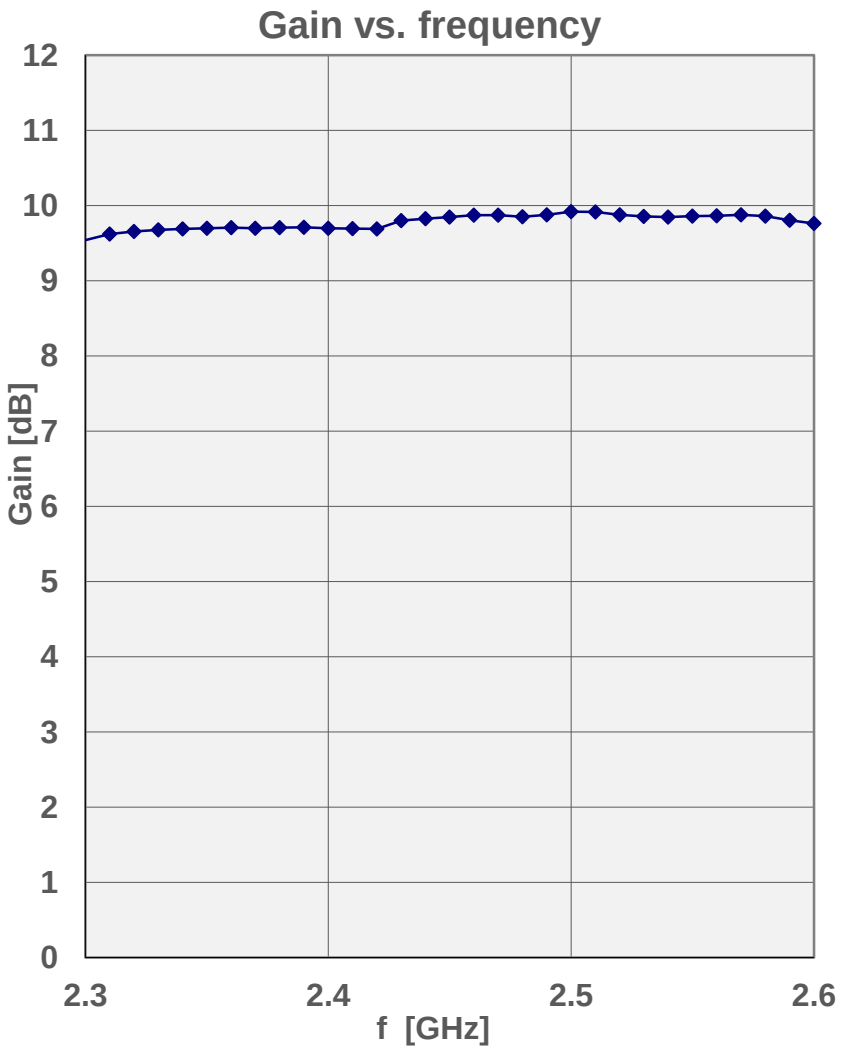
RFX8422S CW Power Detector over Frequency
VDD = 3.3V



Detector voltage measured with 10kΩ load. Detector voltage will vary with different resistor load values.

RFX8422S LNA Gain and Noise Figure vs. Frequency
VDD = 3.3V





RXEN=High, LEN=High, TXEN=BTEN=Low, Iq= 11 mA

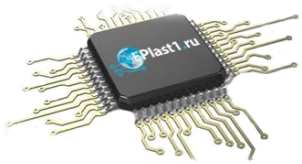
Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits,General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

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